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# PCP1405

## Power MOSFET 250V, 6.5Ω, 0.6A, Single N-Channel

### Features

- On-resistance  $R_{DS(on)} = 5\Omega$  (typ)
- 2.5V drive
- Protection diode in
- Halogen free compliance

### Specifications

#### Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Value	Unit
Drain to Source Voltage	$V_{DSS}$		250	V
Gate to Source Voltage	$V_{GSS}$		$\pm 10$	V
Drain to Gate Voltage	$V_{DGS}$		250	V
Gate to Drain Voltage	$V_{GDS}$		$\pm 10$	V
Drain Current (DC)	$I_D$		0.6	A
Drain Current (Pulse)	$I_{DP}$	$PW \leq 10\mu\text{s}$ , duty cycle $\leq 1\%$	2.4	A
Power Dissipation	$P_D$	$T_c = 25^\circ\text{C}$	3.5	W
		When mounted on ceramic substrate (600mm <sup>2</sup> × 0.8mm)	1.3	W
Junction Temperature	$T_j$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Case Steady State	$R_{\theta JC}$	35.7	$^\circ\text{C/W}$
Junction to Ambient When mounted on ceramic substrate (600mm <sup>2</sup> × 0.8mm)	$R_{\theta JA}$	96.1	

### Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1\text{mA}$ , $V_{GS} = 0\text{V}$	250			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 250\text{V}$ , $V_{GS} = 0\text{V}$			1	$\mu\text{A}$
Gate to Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 8\text{V}$ , $V_{DS} = 0\text{V}$			$\pm 10$	$\mu\text{A}$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = 10\text{V}$ , $I_D = 1\text{mA}$	0.4		1.3	V
Forward Transconductance	$g_{FS}$	$V_{DS} = 10\text{V}$ , $I_D = 0.3\text{A}$		1.4		S

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### ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

# PCP1405

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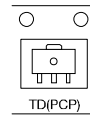
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D=0.3A, V_{GS}=4.5V$		5	6.5	$\Omega$
	$R_{DS(on)2}$	$I_D=0.3A, V_{GS}=2.5V$		5.1	7.2	$\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=20V, f=1MHz$		140		pF
Output Capacitance	$C_{oss}$			8		pF
Reverse Transfer Capacitance	$C_{rss}$			3		pF
Turn-ON Delay Time	$t_{d(on)}$			7.6		ns
Rise Time	$t_r$	See specified Test Circuit		7.8		ns
Turn-OFF Delay Time	$t_{d(off)}$			19		ns
Fall Time	$t_f$			26		ns
Total Gate Charge	$Q_g$	$V_{DS}=125V, V_{GS}=4.5V, I_D=0.6A$		2.1		nC
Gate to Source Charge	$Q_{gs}$			0.3		nC
Gate to Drain "Miller" Charge	$Q_{gd}$			0.7		nC
Forward Diode Voltage	$V_{SD}$	$I_S=0.6A, V_{GS}=0V$		0.84	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

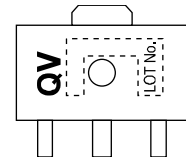
## Ordering & Package Information

Device	Package	Shipping	note
PCP1405-TD-H	PCP, SC-62 SOT-89, TO-243	1,000 pcs. / reel	Pb-Free and Halogen Free

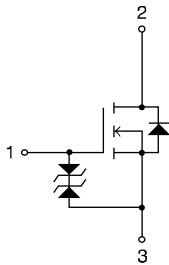
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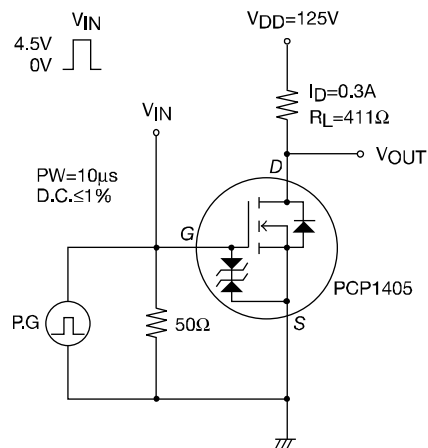
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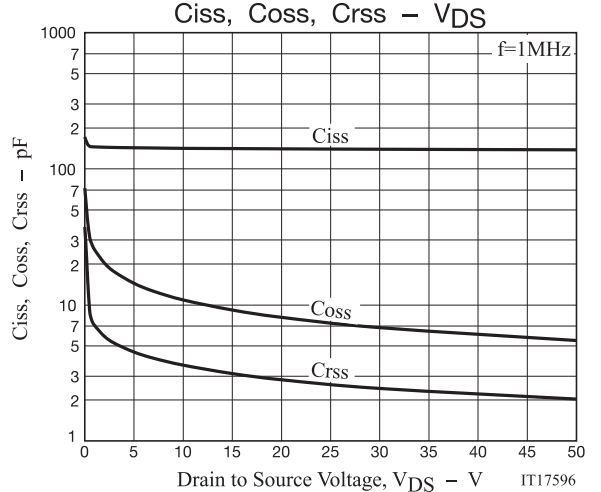
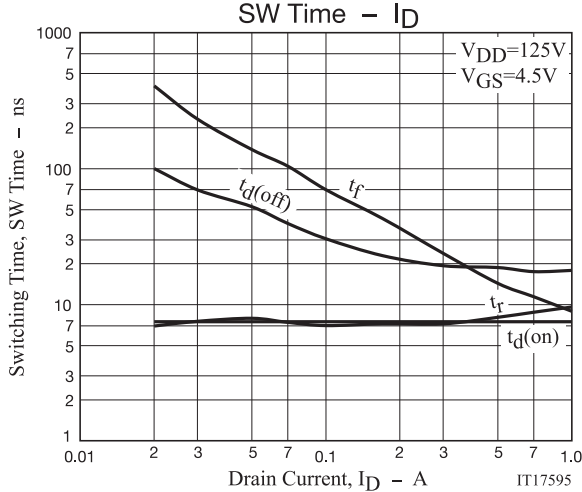
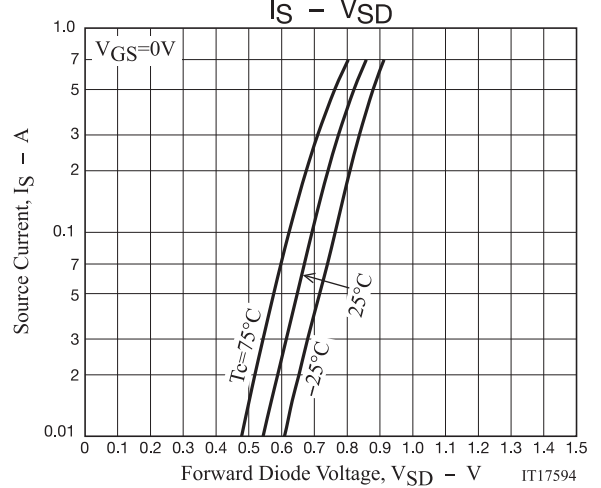
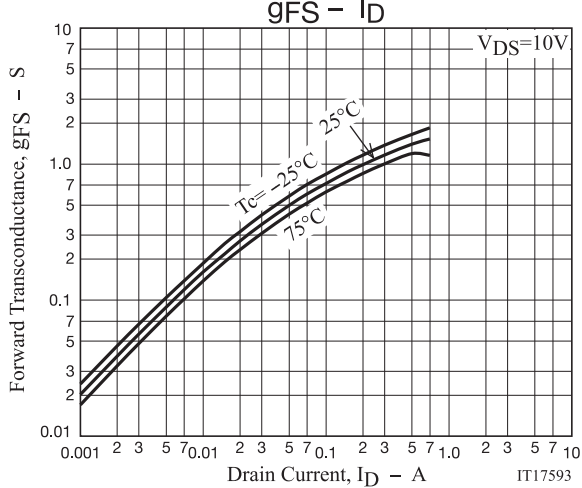
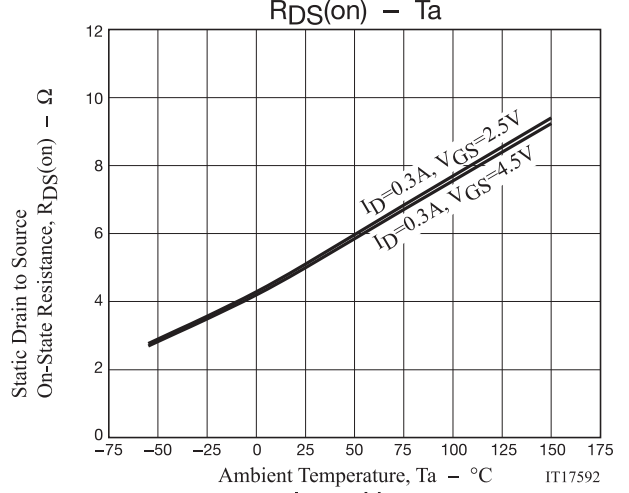
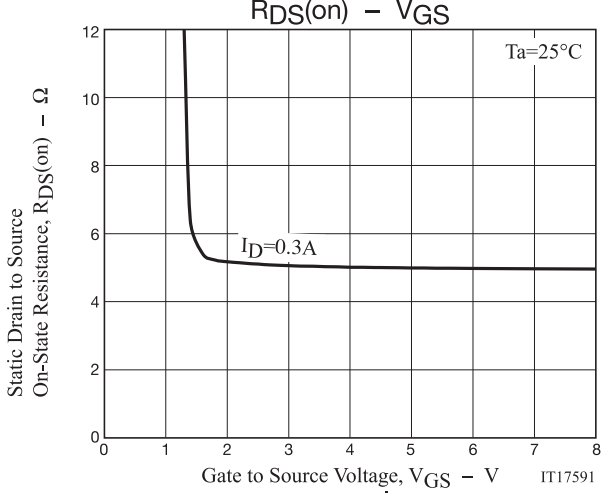
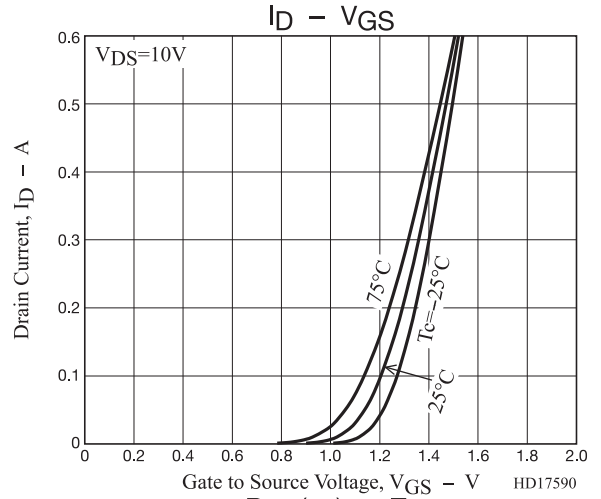
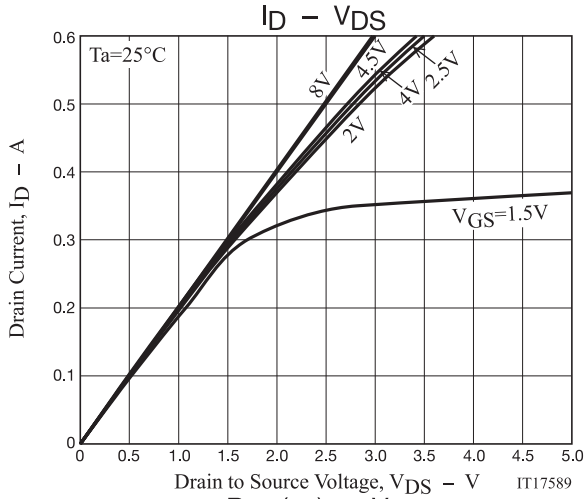


## Electrical Connection

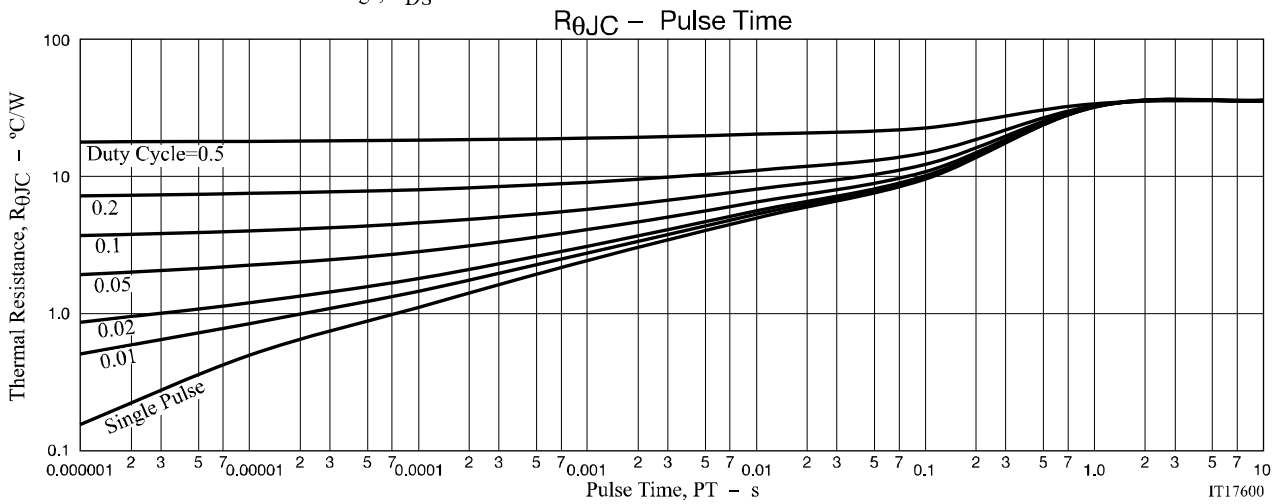
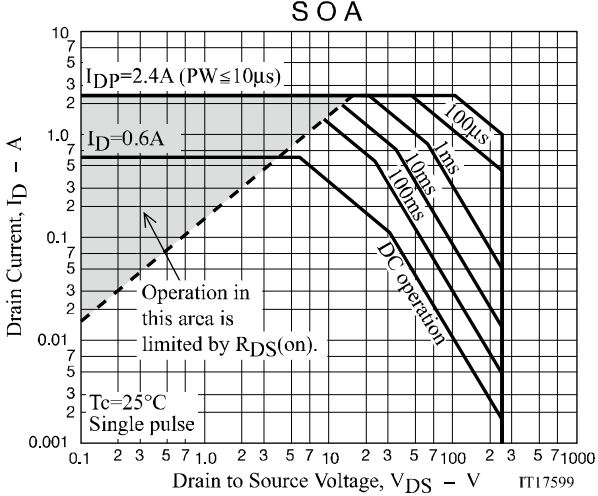
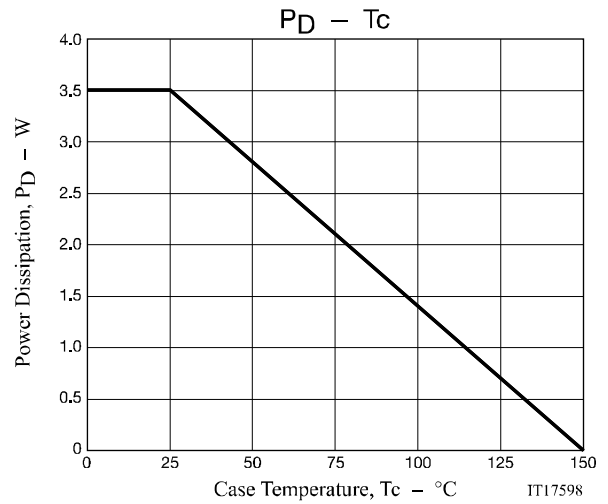
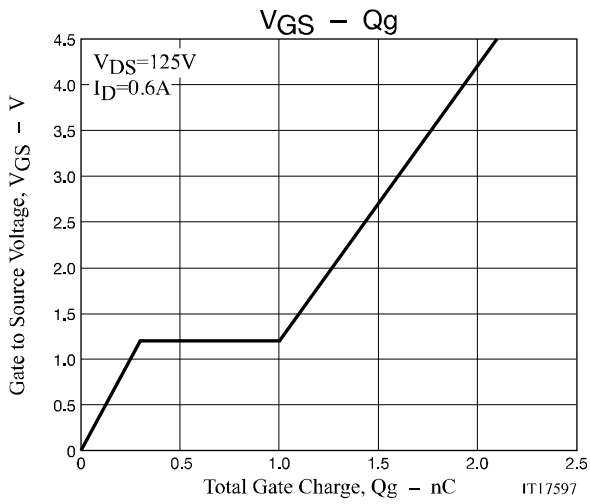


## Switching Time Test Circuit





# PCP1405



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## Package Dimensions

PCP1405-TD-H

### SOT-89/PCP-1

CASE 419AU

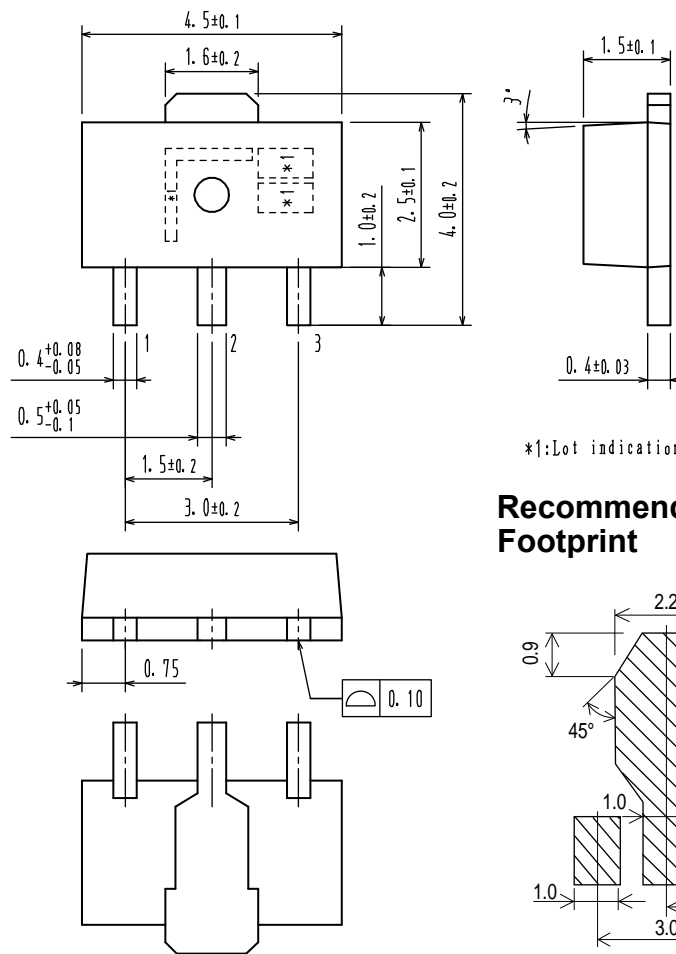
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unit : mm

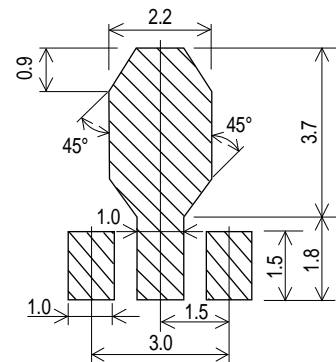
1: Gate

2: Drain

3: Source



### Recommended Soldering Footprint



Note on usage : Since the PCP1405 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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